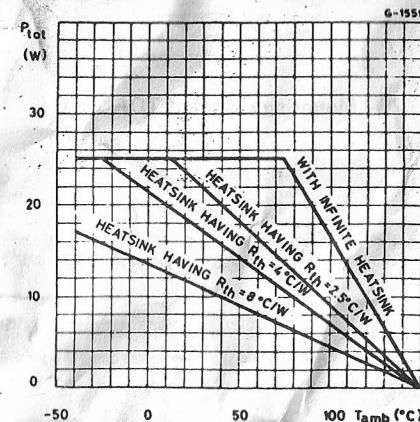


# TDA 2020

The maximum allowable power dissipation depends upon the size of the external heatsink (i.e. its thermal resistance); fig. 28 shows this dissipable power as a function of ambient temperature for different thermal resistance.

Fig.28 - Maximum allowable power dissipation vs. ambient temperature



For a more detailed description of the TDA 2020 and related performance refer to SGS-ATES Application Note n. 130.

# LINEAR INTEGRATED CIRCUIT

# TDA 2020

## PRELIMINARY DATA

### 20 W Hi-Fi AUDIO POWER AMPLIFIER WITH SHORT CIRCUIT PROTECTION AND THERMAL SHUT-DOWN

The TDA 2020 is a monolithic integrated operational amplifier in a 14-lead quad in-line\* plastic package, intended for use as a low frequency class B power amplifier. Typically it provides 20 W output power ( $d = 1\%$ ) at  $\pm 18 \text{ V}/4 \Omega$ ; the guaranteed output power at  $\pm 17 \text{ V}/4 \Omega$  is, 15 W (DIN norm 45500). The TDA 2020 provides high output current (up to 3.5 A) and has very low harmonic and cross-over distortion. Further, the device incorporates an original (and patented) short circuit protection system, comprising an arrangement for automatically limiting the dissipated power so as to keep the working point of the output transistors within their safe operating area. A conventional thermal shut-down system is also included. The TDA 2020 is pin to pin equivalent to TDA 2010.

\*(or, optionally, dual in-line)

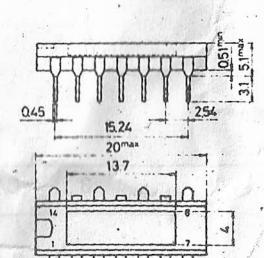
## ABSOLUTE MAXIMUM RATINGS

$V_S$	Supply voltage	$\pm 22$	V
$V_i$	Input voltage	$\pm 15$	V
$V_{i\text{d}}$	Differential input voltage	3.5	A
$I_o$	Output peak current (internally limited)	25	W
$P_{\text{tot}}$	Power dissipation at $T_{\text{case}} \leq 75^\circ\text{C}$	-40 to 150	$^\circ\text{C}$
$T_{\text{stg}}, T_j$	Storage and junction temperature		

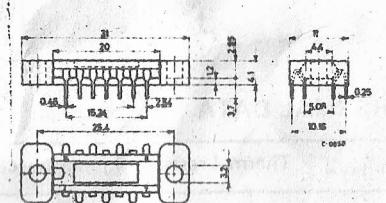
ORDERING NUMBERS: TDA 2020 A82 dual in-line plastic package  
TDA 2020 A92 quad in-line plastic package  
TDA 2020 AC2 dual in-line plastic package with spacer  
TDA 2020 AD2 quad in-line plastic package with spacer

## MECHANICAL DATA

Dimensions in mm

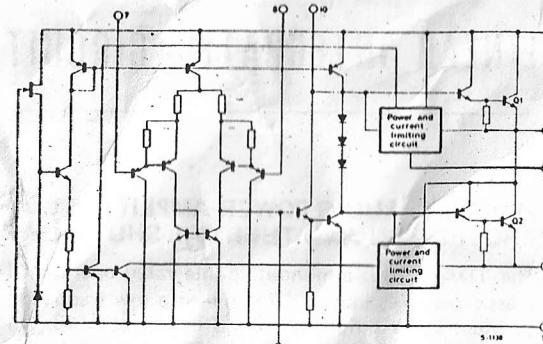
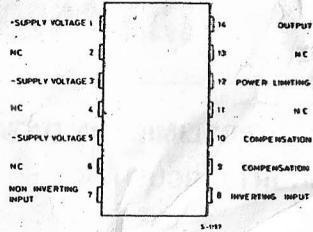


TDA 2020 A92



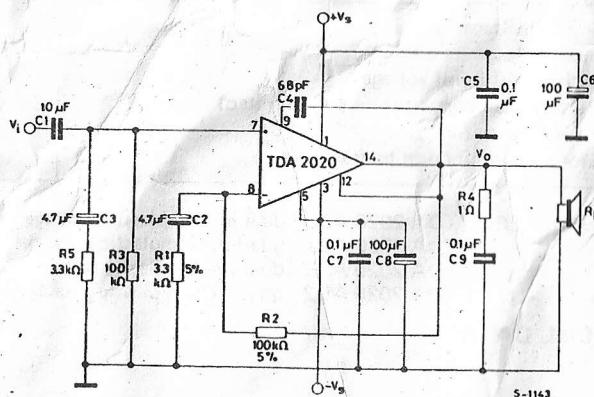
TDA 2020 AD2

## CONNECTION AND SCHEMATIC DIAGRAMS



The copper slug is electrically connected to pin 5 (substrate)

## TEST CIRCUIT



## THERMAL DATA

$R_{th}$ j-case	Thermal resistance junction-case	max	3	$^{\circ}\text{C/W}$
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## ELECTRICAL CHARACTERISTICS

(Refer to the test circuit,  $V_s = \pm 17\text{V}$ ,  $T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified)

Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_s$ Supply voltage		$\pm 5$	$\pm 22$		V
$I_d$ Quiescent drain current	$V_s = \pm 22\text{V}$	60			mA
$I_b$ Bias current		0.15			$\mu\text{A}$
$V_{i(off)}$ Input offset voltage	$V_s = \pm 17\text{V}$	5			mV
$I_{i(off)}$ Input offset current		0.05			$\mu\text{A}$
$V_{o(off)}$ Output offset voltage		10	100		mV
$P_o$ Output power	$d = 1\%$ $T_{case} \leq 70^{\circ}\text{C}$ $f = 40$ to $15,000$ Hz	15	18.5		W
	$V_s = \pm 17\text{V}$ $R_L = 4 \Omega$	20			W
	$V_s = \pm 18\text{V}$ $R_L = 4 \Omega$	16.5			W
	$V_s = \pm 18\text{V}$ $R_L = 8 \Omega$				
	$d = 10\%$ $T_{case} \leq 70^{\circ}\text{C}$ $f = 1$ kHz	24			W
	$V_s = \pm 17\text{V}$ $R_L = 4 \Omega$	20			W
	$V_s = \pm 18\text{V}$ $R_L = 8 \Omega$				
$V_i$ Input sensitivity	$G_v = 30$ dB $P_o = 15\text{W}$ $V_s = \pm 17\text{V}$ $R_L = 4 \Omega$ $V_s = \pm 18\text{V}$ $R_L = 8 \Omega$	260	380		mV mV
B Frequency response(-3dB)	$R_L = 4 \Omega$ $C4 = 68 \text{ pF}$	10 to 160,000			Hz
d Distortion	$P_o = 150 \text{ mW to } 15\text{W}$ $R_L = 4 \Omega$ $G_v = 30$ dB $T_{case} \leq 70^{\circ}\text{C}$ $f = 1$ kHz $f = 40$ to $15,000$ Hz	0.2	0.3	1	% %
	$P_o = 150 \text{ mW to } 15\text{W}$ $V_s = \pm 18\text{V}$ $R_L = 8 \Omega$ $G_v = 30$ dB $T_{case} \leq 70^{\circ}\text{C}$ $f = 1$ kHz $f = 40$ to $15,000$ Hz	0.1	0.25		% %

## ELECTRICAL CHARACTERISTICS (continued)

Parameter	Test conditions	Min.	Typ.	Max.	Unit
$R_I$	Input resistance (pin 7)		5		MΩ
$G_v$	Voltage gain (open loop)		100		dB
$G_v$	Voltage gain (closed loop)	29.5	30	30.5	dB
$e_N$	Input noise voltage	$R_L = 4\Omega$	4		μV
$i_N$	Input noise current	$B(-3 \text{ dB}) = 10 \text{ to } 20,000 \text{ Hz}$	0.1		nA
SVR	Supply voltage rejection ratio	$R_L = 4\Omega$ $f_{\text{ripple}} = 100 \text{ Hz}$	50		dB
$I_d$	Drain current	$P_o = 18.5 \text{ W}$ $R_L = 4\Omega$	1		A
		$P_o = 16.5 \text{ W}$ $V_s = \pm 18 \text{ V}$ $R_L = 8\Omega$	0.7		A
Thermal shut-down junction temperature			145		°C
* Thermal shut-down case temperature	$P_{\text{tot}} = 15.5 \text{ W}$		105		°C

\* See fig. 15

Fig. 1 - Typical output power vs. supply voltage ( $d = 1\%$ )

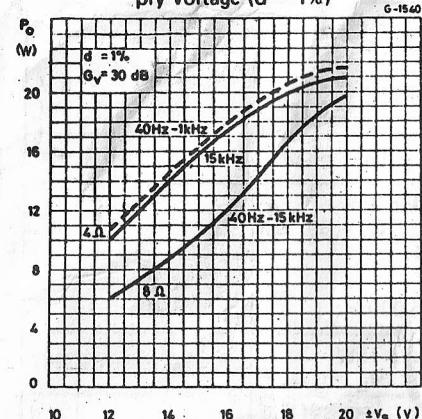
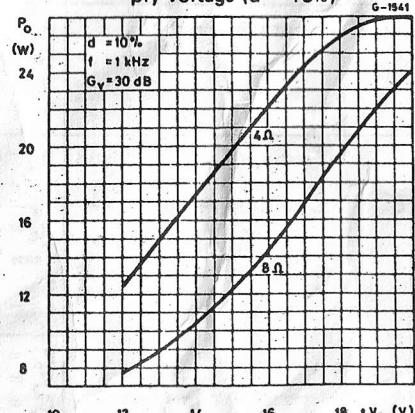


Fig. 2 - Typical output power vs. supply voltage ( $d = 10\%$ )



4

Fig. 3 - Typical distortion vs. output power ( $R_L = 4\Omega$ )

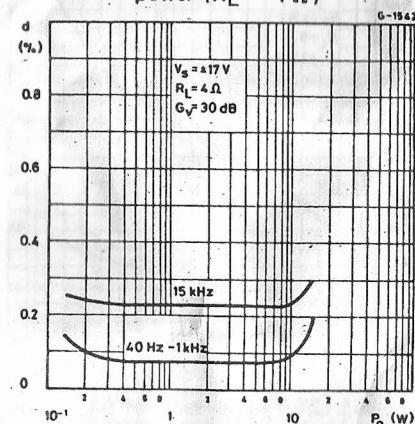


Fig. 5 - Typical distortion vs. output power ( $R_L = 8\Omega$ )

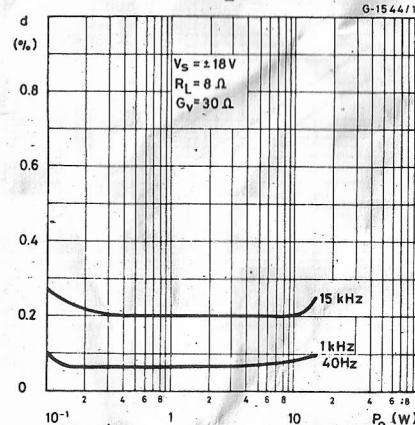


Fig. 7 - Typical distortion vs. frequency

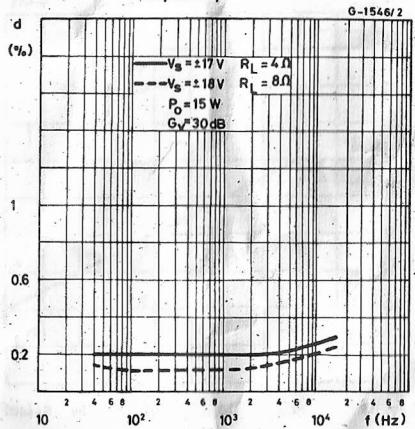


Fig. 4 - Typical distortion vs. output power ( $R_L = 4\Omega$ )

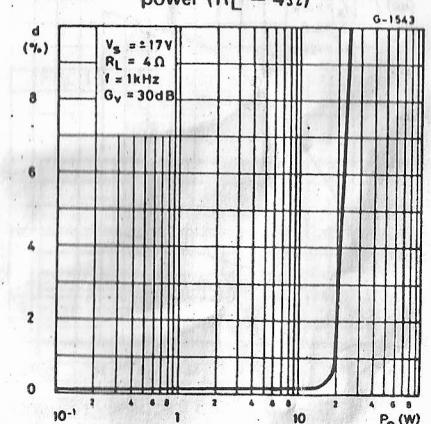


Fig. 6 - Typical distortion vs. output power ( $R_L = 8\Omega$ )

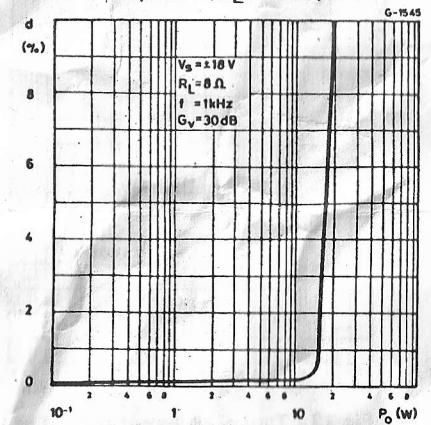
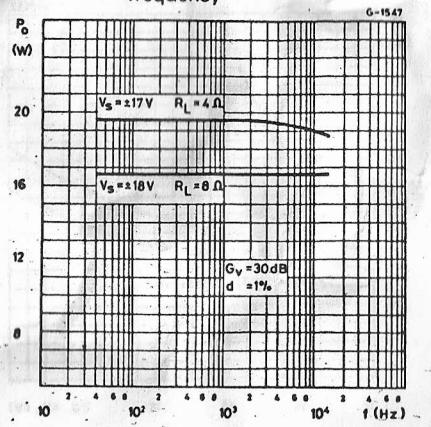


Fig. 8 - Typical output power vs. frequency



5

Fig. 9 - Typical sensitivity vs. output power ( $R_L = 4 \Omega$ ) .

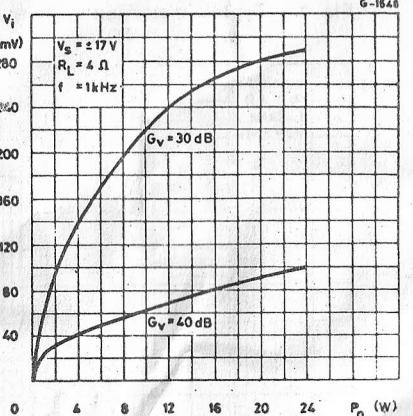


Fig. 11 - Open loop frequency response with different values of the rolloff capacitor C4

Fig. 10- Typical sensitivity vs. output power ( $R_L = 8\Omega$ )

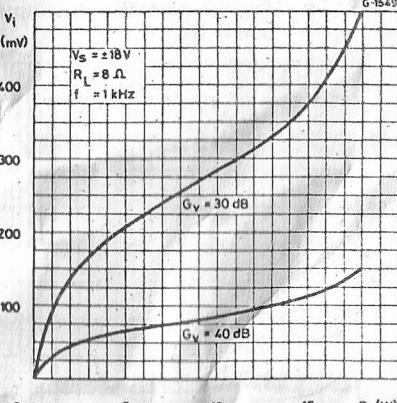


Fig.12 - Typical value of C4 vs. voltage gain for different band-widths

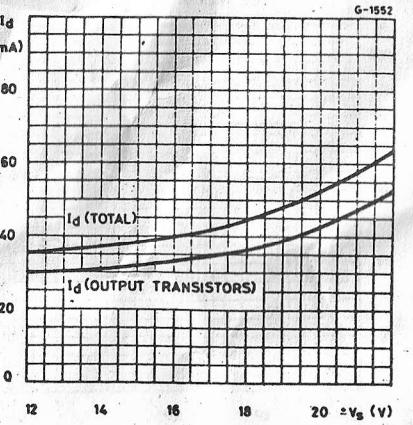


Fig. 14 - Typical supply voltage rejection ratio vs. voltage gain

G-1553

$V_g \approx \pm 17 \text{ V}$

$f_{\text{ripple}} = 100 \text{ Hz}$

$G_v \text{ (dB)}$	$\text{SVR} \text{ (dB)}$
-10	60
0	50
10	40
20	30
30	20
40	10
50	0
60	-10

Fig. 15 - Typical power dissipation and efficiency vs. output power

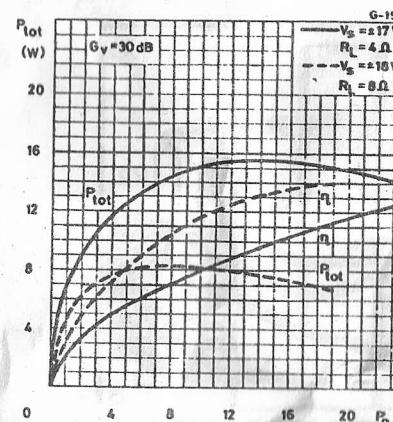
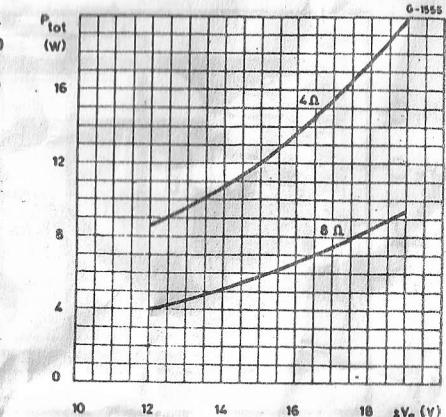


Fig. 16- Maximum power dissipation vs. supply voltage (sine wave operation)



## APPLICATION INFORMATION

Fig. 17 - Typical amplifier with split power supp

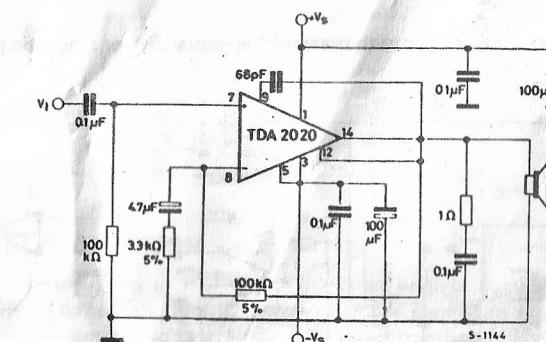


Fig. 18 - P.C. board and component layout for the circuit of fig. 17 (1:1 scale)

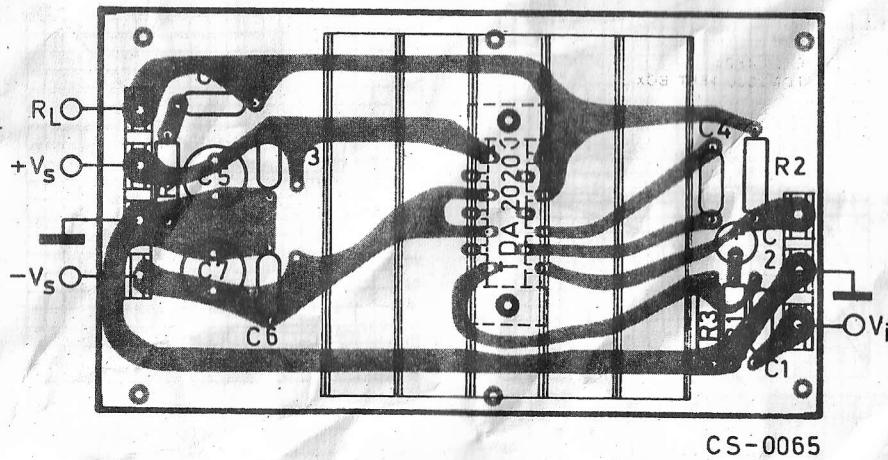


Fig. 19 - 15 W Hi-Fi stereo amplifier with preamplifier-equalizer for magnetic pick-ups

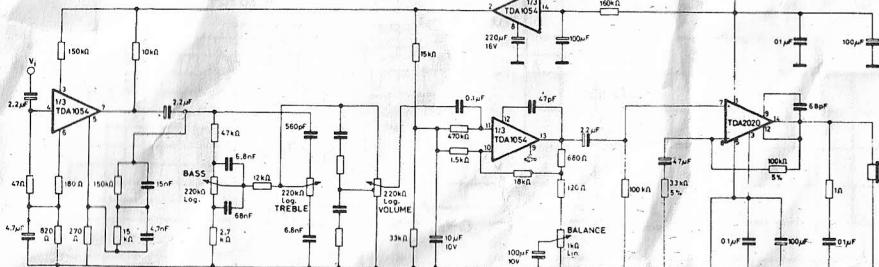


Fig. 20 - Typical stereo amplifier with split power supply

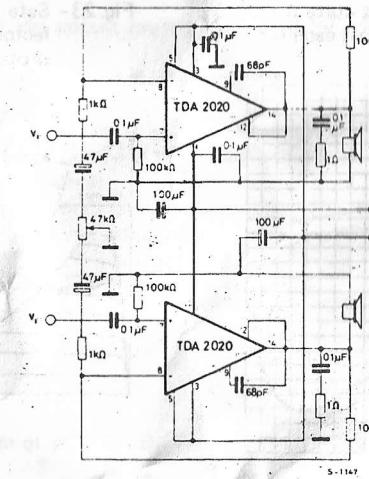
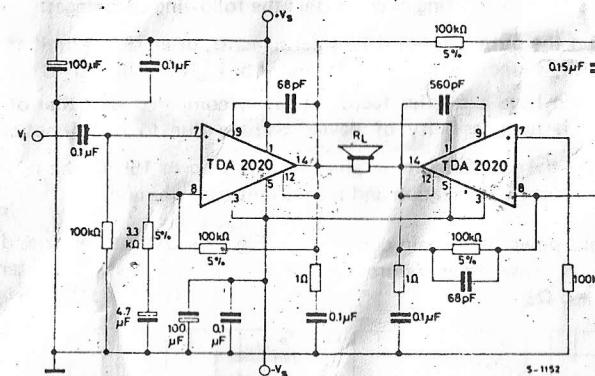


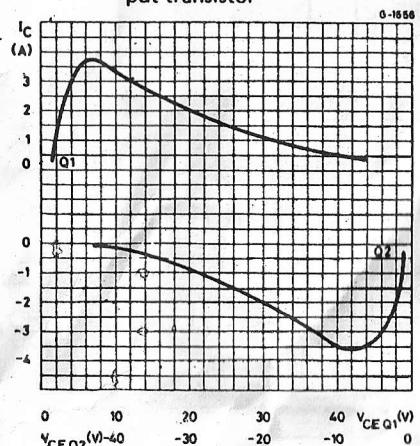
Fig. 21 - Typical bridge amplifier configuration with split power supply ( $R_L = 8\Omega$ ,  $d \leq 1.5$ ;  $P_o = 20 W @ V_s = \pm 14 V$  and  $P_o = 30 W @ V_s = \pm 17V$ )



### SHORT CIRCUIT PROTECTION

The most important innovation in the TDA 2020 is an original circuit which limits the current of the output transistors. Fig. 22 shows that the maximum output current is a function of the collector-emitter voltage; hence the output transistors work within their safe operating area (fig. 23). This function can therefore be considered as being peak power limiting rather than simple current limiting. The TDA 2020 is thus protected against temporary overloads or short circuit. Should the short circuit exists for a longer time, the thermal shut-down comes into action and keeps the junction temperature within safe limits.

Fig.22 - Maximum output current vs. voltage ( $V_{CE}$ ) across each output transistor



### THERMAL SHUT-DOWN

The presence of a thermal limiting circuit offers the following advantages:

- 1) an overload on the output (even if it is permanent), or an above-limit ambient temperature can be easily supported since the  $T_j$  cannot be higher than 150 °C
- 2) the heatsink can have a smaller factor of safety compared with that of a conventional circuit. There is no possibility of device damage due to high junction temperature.

If, for any reason, the junction temperature increases up to 150°C, the thermal shut-down simply reduces the power dissipation and the current consumption.

Fig.24 - Output power and drain current vs. case temperature ( $R_L = 8 \Omega$ )

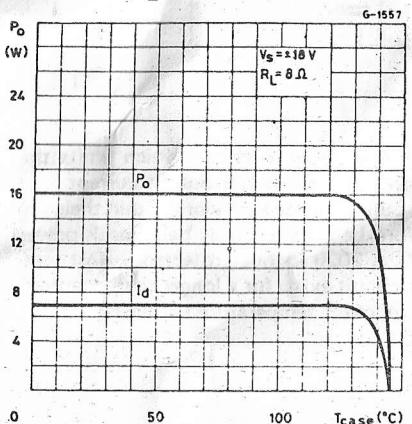
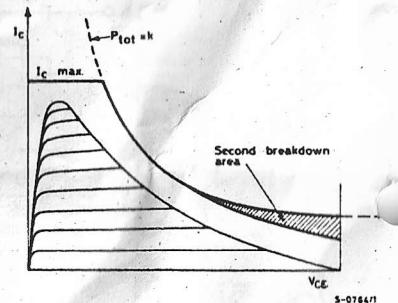


Fig.23 - Safe operating area and collector characteristics of the protected power transistor



### MOUNTING INSTRUCTIONS

The power dissipated in the circuit must be removed by adding an external heatsink as shown in figs. 26 and 27.

The system for attaching the heatsink is very simple: it uses a plastic spacer which is supplied with the device.

Thermal contact between the copper slug (of the package) and the heatsink is guaranteed by the pressure which the screws exert via the spacer and the printed circuit board; this is due to the particular shape of the spacer.

Note: the most negative supply voltage is connected to the copper slug, hence to the heatsink (because it is in contact with the slug).

Fig.26 - Mounting system of TDA 2020

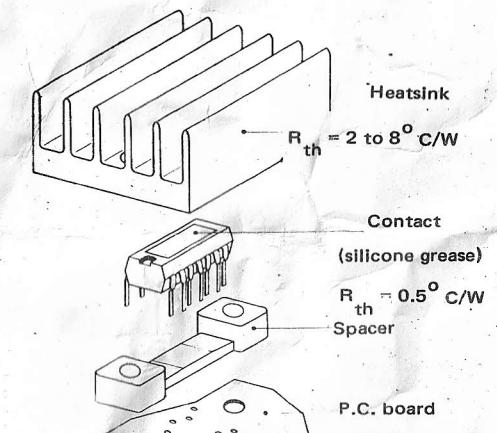


Fig.27 - Cross-section of mounting system

